

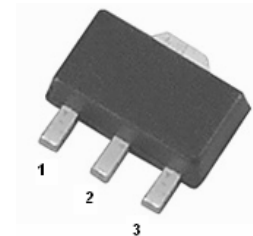
## SMD General Purpose Transistor (PNP)

### Features

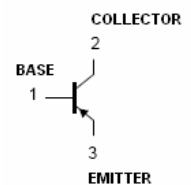
- PNP Silicon Epitaxial Planar Transistor for High Current and Low Voltage Applications

### Mechanical Data

<b>Case:</b>	SOT-89, Plastic Package
<b>Terminals:</b>	Solderable per MIL-STD-202G, Method 208
<b>Weight:</b>	0.015 gram



SOT-89



### Marking Information

Rank	BC869	BC869-16	BC869-25
Marking Code	CEC	CGC	CHC

### Maximum Ratings ( $T_{Ambient}=25^{\circ}C$ unless noted otherwise)

Symbol	Description	Value	Unit
<b>-V<sub>CB0</sub></b>	Collector-Base Voltage	32	V
<b>-V<sub>CEO</sub></b>	Collector-Emitter Voltage	20	V
<b>-V<sub>EB0</sub></b>	Emitter-Base Voltage	5	V
<b>-I<sub>c</sub></b>	Collector Current	1	A
<b>P<sub>D</sub></b>	Power Dissipation	500	mW
<b>T<sub>J</sub></b>	Junction Temperature	150	°C
<b>T<sub>STG</sub></b>	Storage Temperature Range	-65 to +150	°C

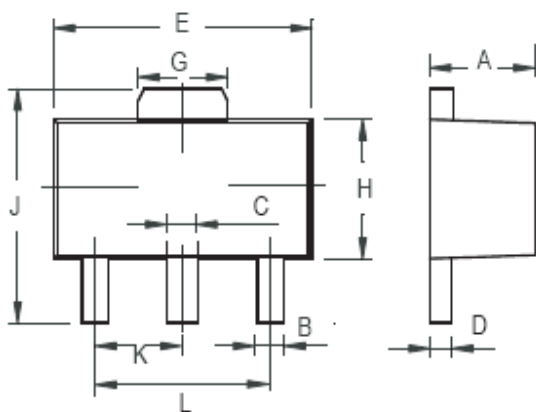
# SMD General Purpose Transistor (PNP)

## BC869

### Electrical Characteristics ( $T_{Ambient}=25^{\circ}C$ unless noted otherwise)

Symbol	Description	Min.	Max.	Unit	Conditions	
$-V_{(BR)CBO}$	Collector-Base Breakdown Voltage	32	-	V	$-I_C=0.1mA, I_E=0$	
$-V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	20	-	V	$-I_C=1mA, I_B=0$	
$-V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	5	-	V	$-I_E=0.1mA, I_C=0$	
$-I_{CBO}$	Collector Cut-off Current	-	0.1	$\mu A$	$-V_{CB}=25V, I_E=0$	
$-I_{EBO}$	Emitter Cut-off Current	-	0.1	$\mu A$	$-V_{EB}=5V, I_C=0$	
<b>hFE</b>	D.C. Current Gain	hFE1	50	-		$-V_{CE}=10V, -I_C=5mA$
		hFE2	100	375		$-V_{CE}=1V, -I_C=500mA$
		hFE3	60	-		$-V_{CE}=1V, -I_C=1A$
		BC869-16	100	250		$-V_{CE}=1V, -I_C=500mA$
		BC869-25	160	375		$-V_{CE}=1V, -I_C=500mA$
$-V_{CE(sat)}$	Collector-Emitter Saturation Voltage	-	0.5	V	$-I_C=1A, -I_B=100mA$	
$-V_{BE(on)}$	Base-Emitter On Voltage	-	1	V	$-V_{CE}=1V, -I_C=1A$	
<b>fT</b>	Current Gain-Bandwidth Product	40	-	MHz	$-V_{CE}=5V, -I_C=10mA, f=100MHz$	

### Dimensions in mm



SOT-89

SOT-89		
Dim	Min	Max
A	1.400	1.600
B	0.320	0.520
C	0.360	0.560
D	0.350	0.440
E	4.400	4.600
G	1.400	1.800
H	2.300	2.600
J	3.940	4.250
K	1.500TYP	
L	2.900	3.100

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BC869

## How to contact us:

### US HEADQUARTERS

28040 WEST HARRISON PARKWAY, VALENCIA, CA 91355-4162

Tel: (800) TAITRON (800) 824-8766 (661) 257-6060

Fax: (800) TAITFAX (800) 824-8329 (661) 257-6415

Email: [taitron@taitroncomponents.com](mailto:taitron@taitroncomponents.com)

Http://[www.taitroncomponents.com](http://www.taitroncomponents.com)

### TAITRON COMPONENTS MEXICO, S.A .DE C.V.

BOULEVARD CENTRAL 5000 INTERIOR 5 PARQUE INDUSTRIAL ATITALAQUIA, HIDALGO C.P.  
42970 MEXICO

Tel: +52-55-5560-1519

Fax: +52-55-5560-2190

### TAITRON COMPONENTS INCORPORATED REPRESENTAÇÕES DO BRASIL LTDA

RUA DOMINGOS DE MORAIS, 2777, 2.ANDAR, SALA 24 SAÚDE - SÃO PAULO-SP 04035-001 BRAZIL

Tel: +55-11-5574-7949

Fax: +55-11-5572-0052

### TAITRON COMPONENTS INCORPORATED, SHANGHAI REPRESENTATIVE OFFICE

METROBANK PLAZA, 1160 WEST YAN' AN ROAD, SUITE 1503, SHANGHAI, 200052, CHINA

Tel: +86-21-5424-9942

Fax: +86-21-5424-9931